#### Nch 30V 80A Middle Power MOSFET

$V_{DSS}$	30V
R <sub>DS(on)</sub> (Max.)	2.3mΩ
I <sub>D</sub>	±80A
$P_D$	30W

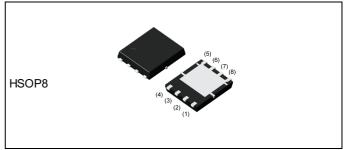
#### Features

- 1) Low on resistance.
- 2) High Power small mold Package (HSOP8).
- 3) Pb-free lead plating; RoHS compliant.
- 4) Halogen Free.

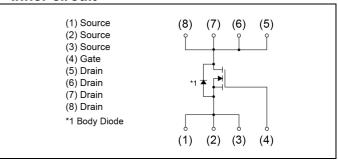
# Application

Switching

#### Outline



#### ●Inner circuit



Packaging specifications

	Packing	Embossed Tape
	Reel size (mm)	330
Туре	Tape width (mm)	12
	Basic ordering unit (pcs)	2500
	Taping code	ТВ
	Marking	RS1E280BN

### ● **Absolute maximum ratings** (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain - Source voltage	V <sub>DSS</sub>	30	V	
Continuous drain surrent	T <sub>c</sub> = 25°C	I <sub>D</sub> *1	±80	Α
Continuous drain current	T <sub>a</sub> = 25°C	I <sub>D</sub>	±28	Α
Pulsed drain current	I <sub>DP</sub> *2	±112	Α	
Gate - Source voltage	$V_{GSS}$	±20	V	
Avalanche current, single pulse		I <sub>AS</sub> *3	48	Α
Avalanche energy, single pulse		E <sub>AS</sub> *3	190	mJ
Down dissinction		P <sub>D</sub> *1	30	W
Power dissipation		P <sub>D</sub> *4	3	W
Junction temperature	T <sub>j</sub>	150	°C	
Operating junction and storage to	T <sub>stg</sub>	-55 to +150	°C	

#### ●Thermal resistance

Doromotor	Curah al	Values			l limit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub> *1	-	-	4.2	°C/W
Thermal resistance, junction - ambient	R <sub>thJA</sub> *4	-	-	41.7	°C/W

# ● Electrical characteristics (T<sub>a</sub> = 25°C)

Daramatar	Parameter Symbol Conditions		Values			Lleit
Parameter			Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 1mA	30	-	-	V
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$	I <sub>D</sub> = 1mA referenced to 25°C	-	21	-	mV/°C
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V	-	-	1	μA
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 16V, V_{DS} = 0V$	1	-	±100	nA
Gate threshold voltage	$V_{GS(th)}$	V <sub>DS</sub> = 10, I <sub>D</sub> = 1mA	1.0	-	2.5	V
Gate threshold voltage temperature coefficient	$\frac{\DeltaV_{GS(th)}}{\DeltaT_j}$	I <sub>D</sub> = 1mA referenced to 25°C	-	-3	-	mV/°C
Static drain - source	D *4	V <sub>GS</sub> = 10V, I <sub>D</sub> = 28A	-	1.7	2.3	O
on - state resistance	R <sub>DS(on)</sub> *4	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 28A	-	2.3	3.2	mΩ
Gate resistance	$R_{G}$	f=1MHz, open drain	-	1.0	-	Ω
Forward Transfer Admittance	Y <sub>fs</sub>  *4	V <sub>DS</sub> = 5V, I <sub>D</sub> = 28A	20	-	-	S

<sup>\*1</sup> Tc=25°C, Limited only by maximum temperature allowed.

<sup>\*2</sup> Pw  $\leq$  10 $\mu$ s, Duty cycle  $\leq$  1%

<sup>\*3</sup> L  $\simeq$  0.05mH,  $V_{DD}$  = 24V,  $R_G$  = 25 $\Omega$ , STARTING  $T_j$  = 25 $^{\circ}$ C Fig.3-1,3-2

<sup>\*4</sup> Mounted on a Cu Board (40×40×0.8mm)

<sup>\*5</sup> Pulsed

### ● Electrical characteristics (T<sub>a</sub> = 25°C)

Darameter	Cumbal	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	5100	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 15V	-	600	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	460	-	
Turn - on delay time	t <sub>d(on)</sub> *4	$V_{DD} \simeq 15V, V_{GS} = 10V$	-	31	-	
Rise time	t <sub>r</sub> *4	I <sub>D</sub> = 14A	1	100	1	no
Turn - off delay time	t <sub>d(off)</sub> *4	R <sub>L</sub> ~ 1.07Ω	-	160	-	ns
Fall time	t <sub>f</sub> *4	$R_G = 10\Omega$		28	-	

# ●Gate charge characteristics (T<sub>a</sub> = 25°C)

Doromotor	Symbol	Canditions		Values			Lloit
Parameter	Parameter Symbol Cor		Conditions		Тур.	Max.	Unit
Total gate charge	O *4		V <sub>GS</sub> = 10V	1	94	1	
Total gate charge	Qg*4	V <sub>DD</sub> ≃ 15V		-	50	-	»C
Gate - Source charge	Q <sub>gs</sub> *4	I <sub>D</sub> = 28A	V <sub>GS</sub> = 4.5V	-	12	-	nC
Gate - Drain charge	Q <sub>gd</sub> *4			-	20	-	

## ●Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Values			Unit	
Parameter	Symbol	I Conditions		Тур.	Max.	UIIIL	
Continuous forward current	I <sub>S</sub>	T = 25°C	-	-	2.5	Α	
Pulse forward current	I <sub>SP</sub> *2	T <sub>a</sub> = 25°C	-	-	112	Α	
Forward voltage	V <sub>SD</sub> *4	$V_{GS} = 0V, I_S = 2.5A$	-	-	1.2	V	

#### Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

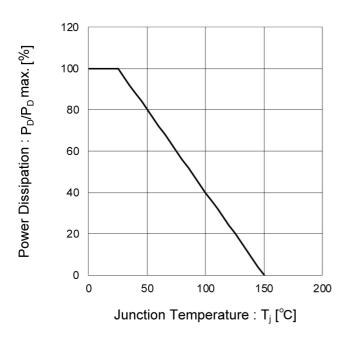
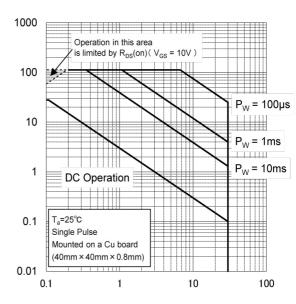


Fig.2 Maximum Safe Operating Area



Drain Current : I<sub>D</sub> [A]

Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

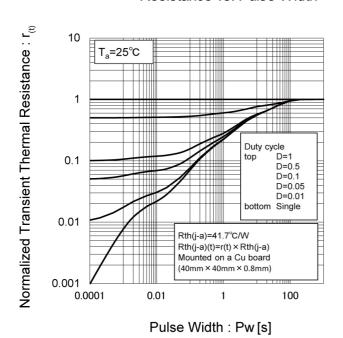
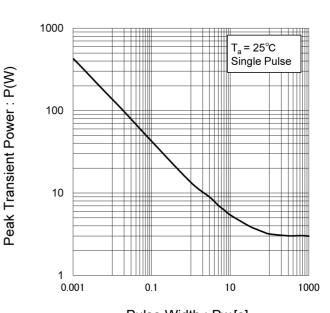


Fig.4 Single Pulse Maximum Power dissipation

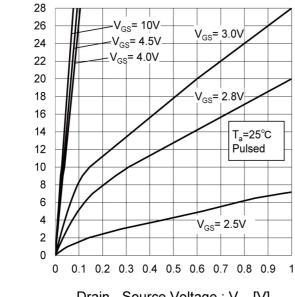


Pulse Width : Pw [s]

Drain Current : I<sub>D</sub> [A]

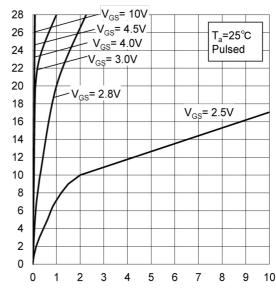
#### Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)



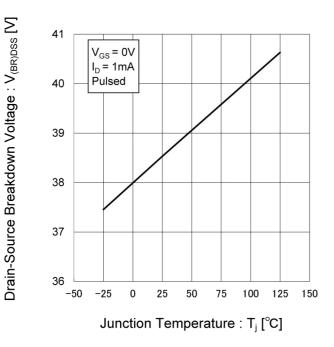
Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.6 Typical Output Characteristics(II)



Drain - Source Voltage : V<sub>DS</sub> [V]

Fig.7 Breakdown Voltage vs. Junction Temperature



Drain Current : I<sub>D</sub> [A]

Drain Current : I<sub>D</sub> [A]

100  $V_{DS}=10V$ Pulsed 10 1 0.1 ≦T<sub>a</sub>= 125℃ \_T<sub>a</sub>= 25°C T<sub>a</sub>= - 25°C 0.01 0.001 0 0.5 1.5 2.5 3 Gate - Source Voltage : V<sub>GS</sub> [V]

Fig.8 Typical Transfer Characteristics

#### • Electrical characteristic curves

Fig.9 Gate Threshold Voltage vs. Junction Temperature

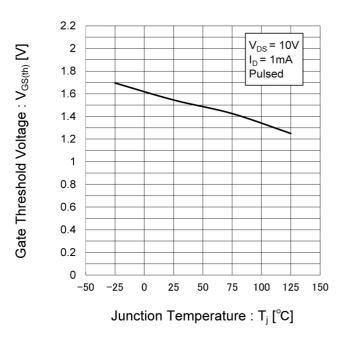


Fig.10 Forward Transfer Admittance vs. Drain Current

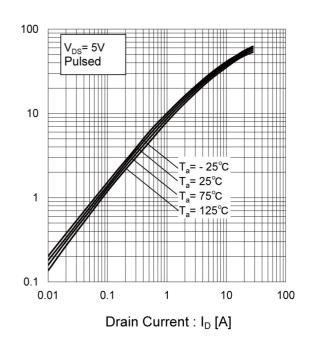


Fig.11 Drain Current Derating Curve

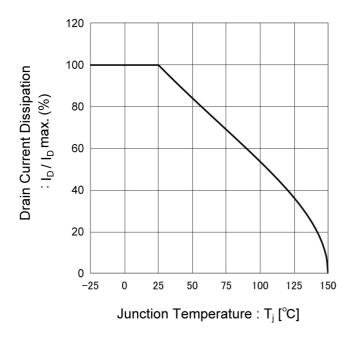
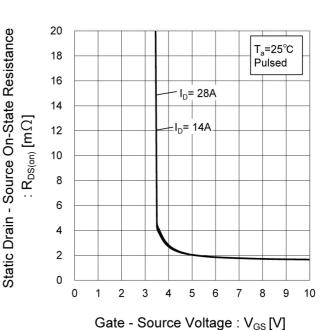


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



Forward Transfer Admittance : Y<sub>fs</sub> [S]

#### • Electrical characteristic curves

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

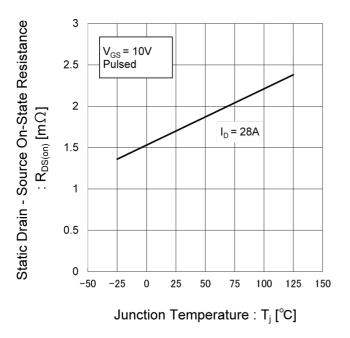


Fig.14 Static Drain - Source On - State Resistance vs. Drain Current(I)

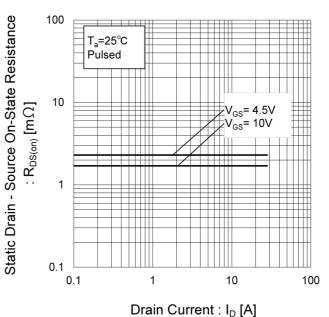


Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(II)

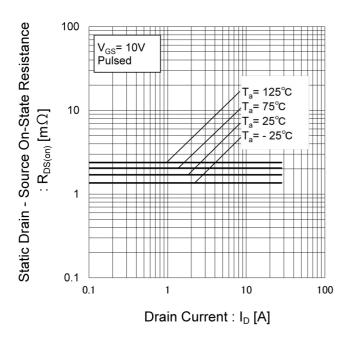
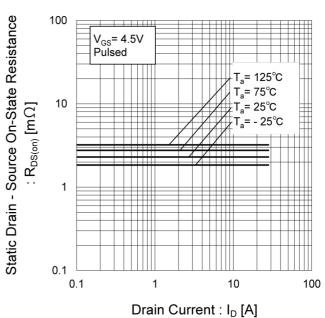


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(III)



### • Electrical characteristic curves

Fig.17 Typical Capacitance vs. Drain - Source Voltage

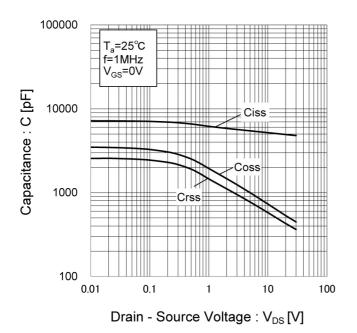


Fig.18 Switching Characteristics

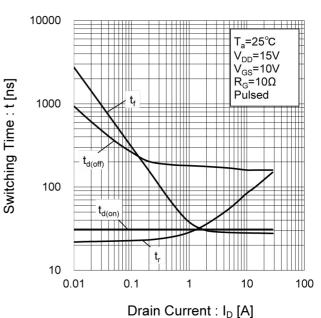


Fig.19 Dynamic Input Characteristics

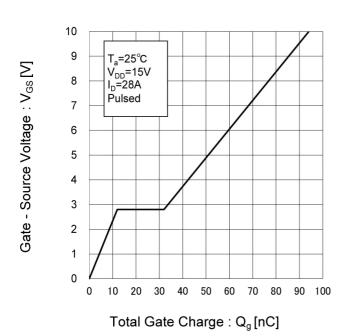
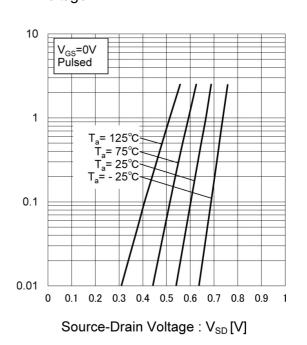


Fig.20 Source Current vs. Source Drain Voltage



Source Current : Is [A]

### Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

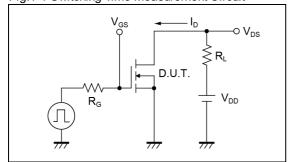


Fig.2-1 Gate Charge Measurement Circuit

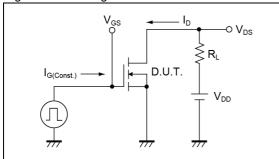


Fig.3-1 Avalanche Measurement Circuit

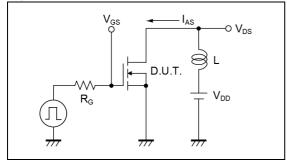


Fig.1-2 Switching Waveforms

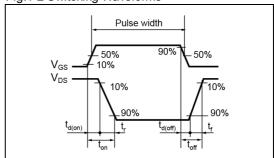


Fig.2-2 Gate Charge Waveform

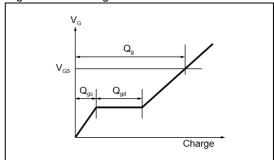
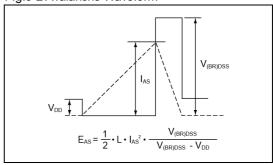


Fig.3-2 Avalanche Waveform

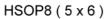


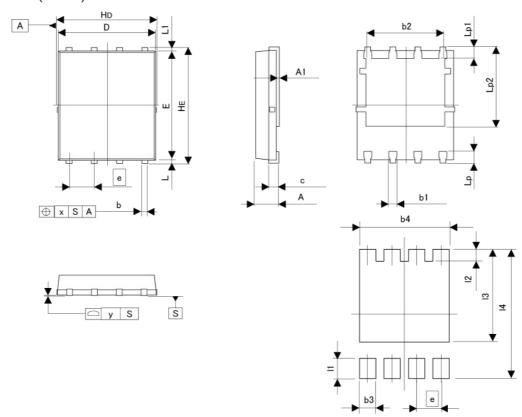
#### Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.



#### Dimensions





Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIME	TERS	INC	HES	
DIIVI	MIN	MAX	MIN	MAX	
Α	0.90	1.10	0.035	0.043	
A1	0.00	0.05	0.000	0.002	
b	0.24	0.42	0.009	0.017	
b1	0.29	0.49	0.011	0.019	
b2	3.81	4.21	0.150	0.166	
С	0.20	0.30	0.008	0.012	
D	4.80	5.00	0.189	0.197	
E	5.60	5.80	0.220	0.228	
е	1.3	27	0.0	50	
HD	4.90	5.10	0.193	0.201	
HE	5.90	6.10	0.232	0.240	
L	0.07	0.25	0.003	0.010	
L1	0.07	0.25	0.003	0.010	
Lp	0.50	0.70	0.020	0.028	
Lp1	0.52	0.72	0.020	0.028	
Lp2	3.92	4.32	0.154	0.170	
х	-	0.10	-	0.004	
у	-	0.10		0.004	

DIM	MILIME	ETERS	INCHES	
DIIVI	MIN	MAX	MIN	MAX
b3	-	0.59		0.023
b4	-	4.21	1	0.166
11	-	0.80	1	0.031
12	-	0.82		0.032
13	-	4.32		0.170
14	2	6.10		0.240

Dimension in mm/inches



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CLASSⅢ	CLASSⅢ	CLASS II b	CL ACCIII
CLASSIV	CLASSIII	CLASSⅢ	CLASSIII

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  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### **Precautions Regarding Application Examples and External Circuits**

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### **Precaution for Storage / Transportation**

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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